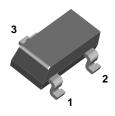
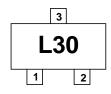
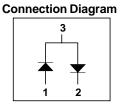


BAV23S







SOT-23

Small Signal Diode

Absolute Maximum Ratings* T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	250	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 microsecond Pulse Width = 100 microsecond	9.0 3.0	A A
T _{stg}	Storage Temperature Range	-55 to +150	°C
TJ	Operating Junction Temperature	150	°C

 $^{{}^{\}textstyle \star} \text{These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.}$

Thermal Characteristics

Symbol	Parameter	Value	Units
P_{D}	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient 357		°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	$I_R = 100 \mu A$	250		V
V _F	Forward Voltage	I _F = 100 mA I _F = 200 mA		1.0 1.25	V V
I _R	Reverse Current	V _R = 250 V V _R = 250 V, T _A = 150°C		100 100	nA μA
t _{rr}	Reverse Recovery Time	$I_F = I_R = 30 \text{ mA}, I_{RR} = 3.0 \text{ mA},$ $R_L = 100 \Omega$		50	ns

Small Signal Diode

(continued)

Typical Characteristics

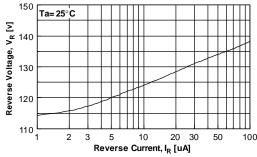


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100 uA

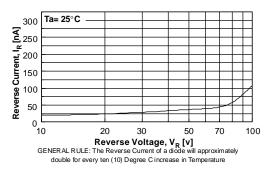


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

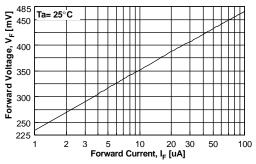


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

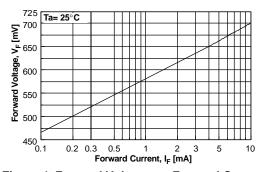


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

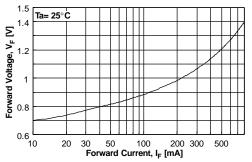


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

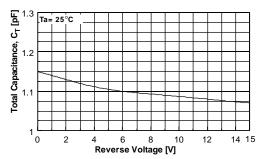


Figure 6. Total Capacitance

Small Signal Diode

(continued)

Typical Characteristics (continued)

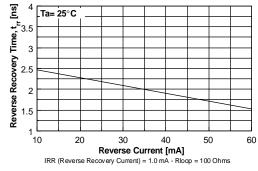


Figure 7. Reverse Recovery Time vs Reverse Current TRR - IR 10 mA vs 60 mA

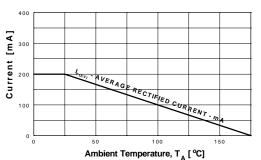
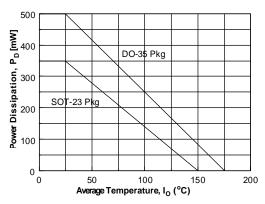


Figure 8. Average Rectified Current (IF(AV))
versus Ambient Temperature (TA)



Figrue 9. Power Derating Curve

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